

SILICON POWER TRANSISTOR **2SD1033**

NPN SILICON EPITAXIAL TRANSISTOR

DESCRIPTION

The 2SD1033 is designed for Color TV vertical deflection output, especially in Hybrid Integrated Circuits.

FEATURES

- High Voltage VCEO = 150 V
- Complement to 2SB768

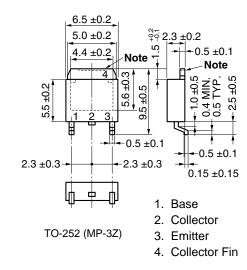
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Collector to Base Voltage	Vсво	200	V
Collector to Emitter Voltage	VCEO	150	V
Emitter to Base Voltage	VEBO	5	V
Collector Current (DC)	IC(DC)	2	А
Collector Current (pulse) Note 1	C(pulse)	3	А
Total Power Dissipation $(T_A = 25^{\circ}C)^{Note 2}$	Р⊤	2.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Notes 1. PW \leq 10 ms, Duty Cycle $\leq 50\%$

2. When mounted on ceramic substrate of 7.5 $\text{cm}^2 \times 0.7 \text{ mm}$

<R> PACKAGE DRAWING (Unit: mm)



Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

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The mark <R> shows major revised points.

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ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

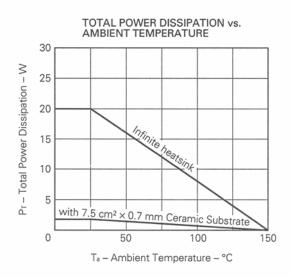
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	Ісво			50	μA	$V_{CB} = 150 V, I_E = 0$
Emitter Cutoff Current	Іево			50	μA	VEB = 4 V, Ic = 0
DC Current Gain	hfe ***	40	100	200		Vce = 10 V, Ic = 0.4 A
Collector Saturation Voltage	VCE(sat) ***		0.2	1.0	V	lc = 500 mA, lв = 50 mA
Gain Bandwidth Product	fт		10		MHz	Vce = 10 V, Ie = 0.4 A

***Pulsed: PW \leq 350 μ s, Duty Cycle \leq 2 %

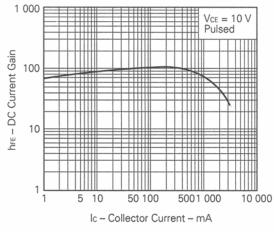
hFE Classification

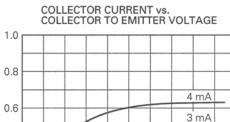
MARKING	м	L	К
hfe	40 to 80	60 to 120	100 to 200

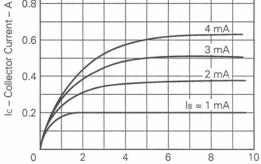
TYPICAL CHARACTERISTICS (Ta = 25 °C)





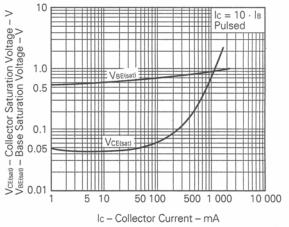


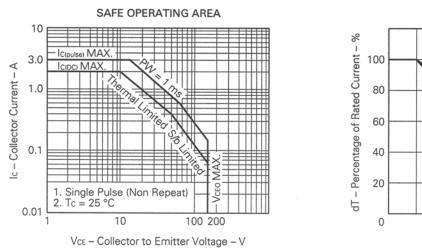


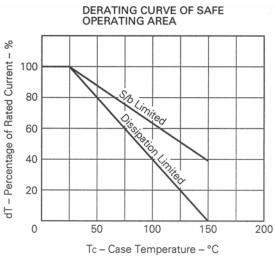


VCE - Collector to Emitter Voltage - V

BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT







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